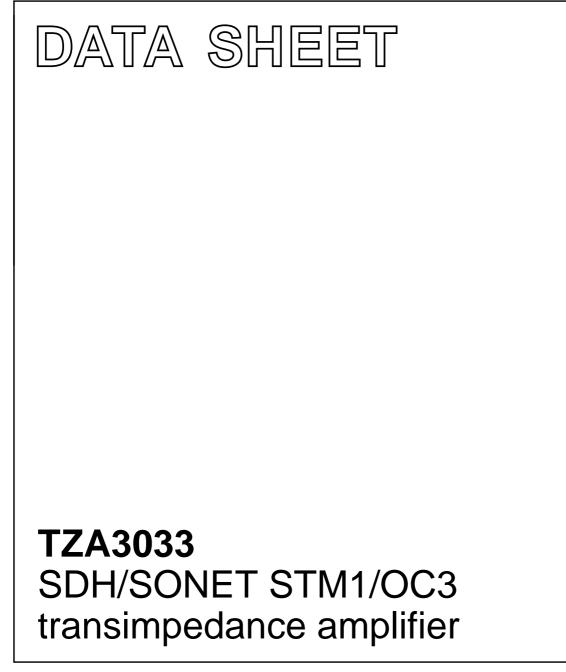
INTEGRATED CIRCUITS



Objective specification File under Integrated Circuits, IC19 1998 Jul 08



TZA3033

FEATURES

- Low equivalent input noise, typically 1 pA/ \sqrt{Hz}
- Wide dynamic range, typically 0.25 μA to 1.6 mA
- Differential transimpedance of 117 $\mbox{k}\Omega$
- Bandwidth minimum 150 MHz
- Differential outputs
- On-chip AGC (Automatic Gain Control)
- No external components required
- Single supply voltage from 3.0 to 5.5 V
- Bias voltage for PIN diode
- Pin compatible with SA5223.

APPLICATIONS

- Digital fibre optic receiver in short, medium and long haul optical telecommunications transmission systems or in high speed data networks
- Wideband RF gain block.

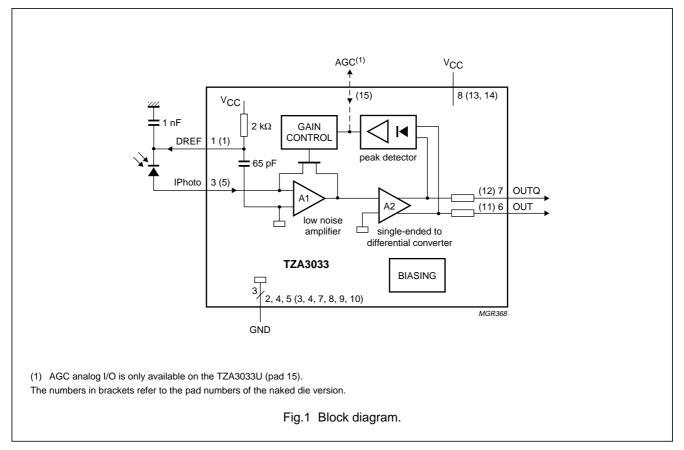
GENERAL DESCRIPTION

The TZA3033 is a low-noise transimpedance amplifier with AGC designed to be used in STM1/OC3 fibre optic links. It amplifies the current generated by a photo detector (PIN diode or avalanche photodiode) and converts it to a differential output voltage.

ORDERING INFORMATION

TYPE		PACKAGE				
NUMBER	NAME	DESCRIPTION	VERSION			
TZA3033T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1			
TZA3033U	naked die	die in waffle pack carriers; die dimensions 0.960×1.210 mm	—			

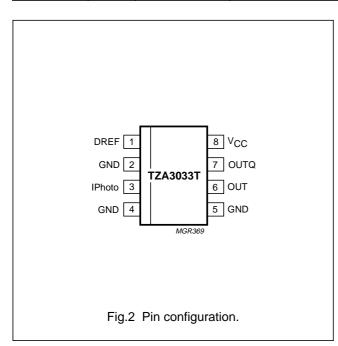
BLOCK DIAGRAM



TZA3033

PINNING

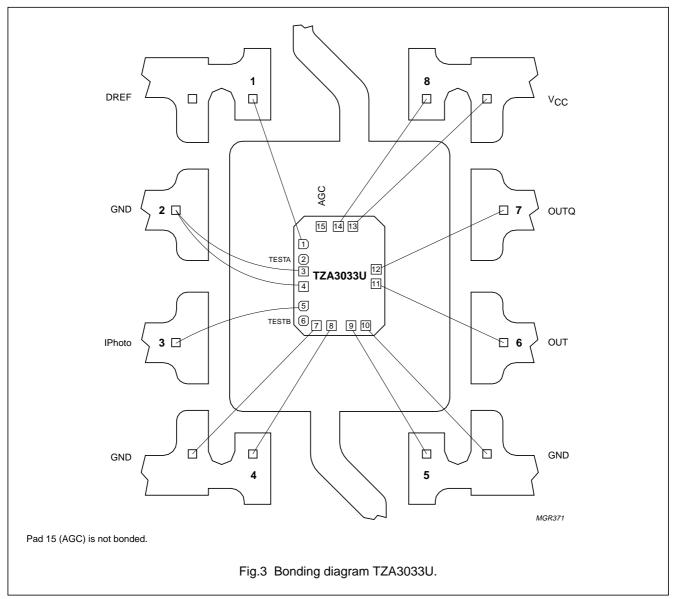
SYMBOL	PIN	ТҮРЕ	DESCRIPTION
DREF	1	analog output	bias voltage for PIN diode (V_{CC}); cathode should be connected to this pin
GND	2	ground	ground
IPhoto	3	analog input	current input; anode of PIN diode should be connected to this pin; DC bias voltage is 1048 mV
GND	4	ground	ground
GND	5	ground	ground
OUT	6	data output	data output; OUT goes HIGH when current flows into IPhoto (pin 3)
OUTQ	7	data output	compliment of OUT (pin 6)
V _{CC}	8	supply	supply voltage



TZA3033

PAD CONFIGURATION

Bonding pad locations



TZA3033

Pad centre locations

SYMBOL	PAD	COORDI	NATES ⁽¹⁾	
STNIDUL	FAD	x	У	
DREF	1	95	881	
TESTA	2	95	735	
GND	3	95	618	
GND	4	95	473	
IPhoto	5	95	285	
TESTB	6	95	147	
GND	7	215	95	
GND	8	360	95	
GND	9	549	95	
GND	10	691	95	
OUT	11	785	501	
OUTQ	12	785	641	
V _{CC}	13	567	1055	
V _{CC}	14	424	1055	
AGC	15	259	1055	

Note

1. All coordinates (μm) are measured with respect to the bottom left-hand corner of the die.

FUNCTIONAL DESCRIPTION

The TZA3033 is a transimpedance amplifier intended for use in fibre optic links for signal recovery in STM1/OC3 applications. It amplifies the current generated by a photo detector (PIN diode or avalanche photodiode) and transforms it into a differential output voltage. The most important characteristics of the TZA3033 are high receiver sensitivity and wide dynamic range.

High receiver sensitivity is achieved by minimizing noise in the transimpedance amplifier.

The signal current generated by a PIN diode can vary between 0.25 μ A to 1.6 mA (peak-to-peak value). An AGC loop (see Fig.1) is implemented to make it possible to handle such a wide dynamic range. The AGC loop increases the dynamic range of the receiver by reducing the feedback resistance of the preamplifier. The AGC loop hold capacitor is integrated on-chip, so an external capacitor is not needed for AGC.

The AGC voltage can be monitored at pad 15 on the naked die (TZA3033U). Pad 15 is not bonded in the packaged device (TZA3033T). This pad can be left unconnected during normal operation. It can also be used to force an external AGC voltage. If pad 15 (AGC) is connected to V_{CC} , the internal AGC loop is disabled and the receiver gain is at a maximum. The maximum input current is then about 10 μ A.

A differential amplifier converts the output of the preamplifier to a differential voltage. The data output circuit is given in Fig.4.

The logic level symbol definitions are shown in Fig.5.

TZA3033

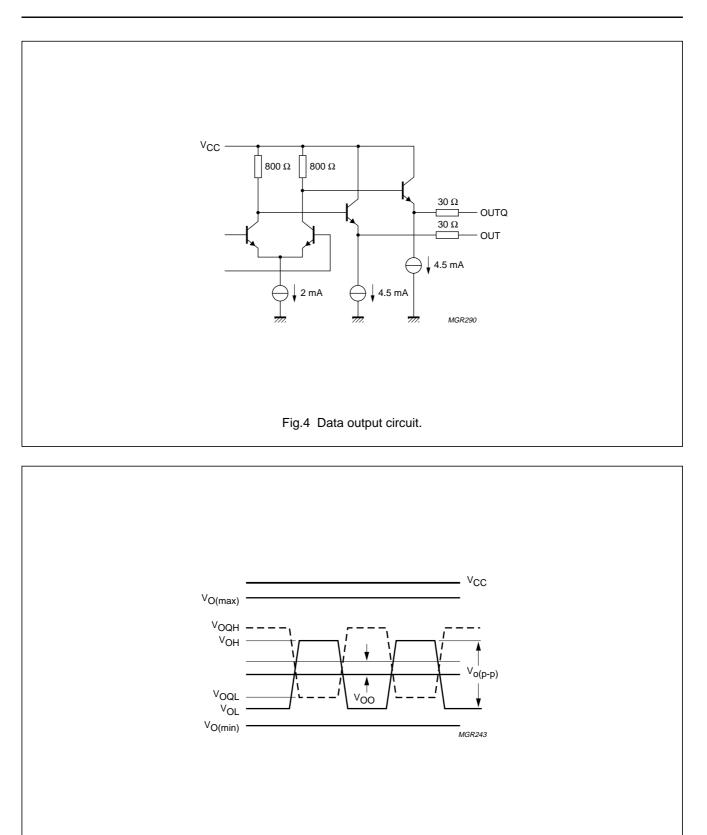


Fig.5 Logic level symbol definitions for data outputs OUT and OUTQ.

TZA3033

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{CC}	supply voltage	-0.5	+5.5	V
V _n	DC voltage			
	pin 3/pad 5: IPhoto	-0.5	+2	V
	pins 6 and 7/pads 11 and 12: OUT and OUTQ	-0.5	V _{CC} + 0.5	V
	pad 15: AGC (TZA3033U only)	-0.5	V _{CC} + 0.5	V
	pin 1/pad 1: DREF	-0.5	V _{CC} + 0.5	V
l _n	DC current			
	pin 3/pad 5: IPhoto	-1	+2.5	mA
	pins 6 and 7/pads 11 and 12: OUT and OUTQ	–15	+15	mA
	pad 15: AGC (TZA3033U only)	-0.2	+0.2	mA
	pin 1/pad 1: DREF	-2.5	+2.5	mA
P _{tot}	total power dissipation	_	300	mW
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	-	150	°C
T _{amb}	ambient temperature	-40	+85	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th(j-s)}	thermal resistance from junction to solder point	tbf	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	tbf	K/W

CHARACTERISTICS

For typical values $T_{amb} = 25 \text{ °C}$ and $V_{CC} = 5 \text{ V}$; minimum and maximum values are valid over the entire ambient temperature range and process spread.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CC}	supply voltage		3	5	5.5	V
I _{CC}	supply current	AC coupled; $R_L = 50 \Omega$	-	37	-	mA
P _{tot}	total power dissipation	$V_{CC} = 5 V$	-	185	-	mW
		V _{CC} = 3.3 V	-	116	_	mW
Tj	junction temperature		-40	-	+120	°C
T _{amb}	ambient temperature		-40	+25	+85	°C
R _{tr}	small-signal transresistance of the	measured differentially; AC coupled				
	receiver	R _L = ∞	-	234	-	kΩ
		$R_L = 50 \Omega$	-	117	_	kΩ
f _{-3dB(h)}	high frequency –3 dB point	C _i = 0.7 pF	120	150	-	MHz

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{n(tot)}	total integrated RMS	referred to input; note 1				
. ,	noise current over	∆f = 90 MHz	_	16	_	nA
	bandwidth	∆f = 120 MHz	_	tbf	_	nA
		$\Delta f = 150 MHz$	_	tbf	_	nA
$\Delta R_{tr} / \Delta t$	AGC loop constant		-	1	-	dB/ms
PSRR	power supply rejection ratio	measured differentially; note 2				
		f = 100 kHz to 10 MHz	_	0.5	_	μA/V
		f = 100 MHz	_	10	-	μA/V
Input: IPho	to					
I _{i(IPhoto)(p-p)}	input current on	$V_{CC} = 5 V$	-500	+1	+1800	μA
	pin IPhoto (peak-to-peak value)	V _{CC} = 3.3 V	-500	+1	+1600	μA
V _{bias} (IPhoto)	input bias voltage on pin IPhoto		-	1048	-	mV
Data outpu	ts: OUT and OUTQ					
V _{O(CM)}	common mode output voltage	AC coupled; $R_L = 50 \Omega$	V _{CC} – 1.800	V _{CC} – 1.700	V _{CC} - 1.600	V
V _{o(se)(p-p)}	single-ended output voltage (peak-to-peak value)	AC coupled; $R_L = 50 \Omega$	-	150	260	mV
V _{OO}	differential output offset voltage		-100	-	+100	mV
R _o	output resistance	single-ended; DC tested	42	50	58	Ω
t _r	rise time	20% to 80%	-	tbf	-	ps
t _f	fall time	80% to 20%	-	tbf	-	ps

Notes

1. All $I_{n(tot)}$ measurements were made with an input capacitance of $C_i = 1 \text{ pF}$. This was comprised of 0.5 pF for the photodiode itself, with 0.3 pF allowed for the printed-circuit board layout and 0.2 pF intrinsic to the package.

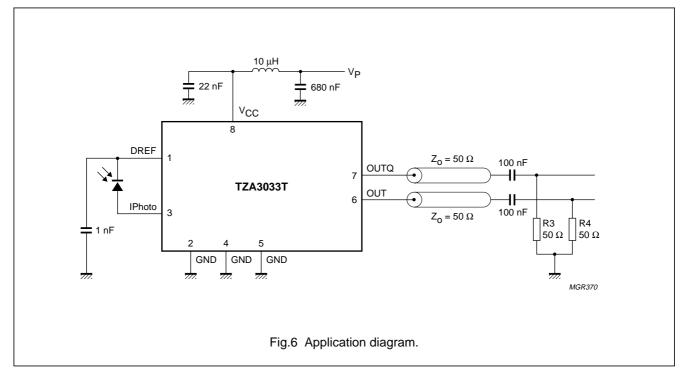
2. PSRR is defined as the ratio of the equivalent current change at the input (ΔI_{IPhoto}) to a change in supply voltage:

$$\mathsf{PSRR} = \frac{\Delta \mathsf{I}_{\mathsf{IPhoto}}}{\Delta \mathsf{V}_{\mathsf{CC}}}$$

For example, a disturbance of +4 mV disturbance on V_{CC} at 10 MHz will typically add an extra 2 nA to the photodiode current. The external capacitor between DREF and GND has a large impact on PSRR. The specification is valid with an external capacitor of 1 nF.

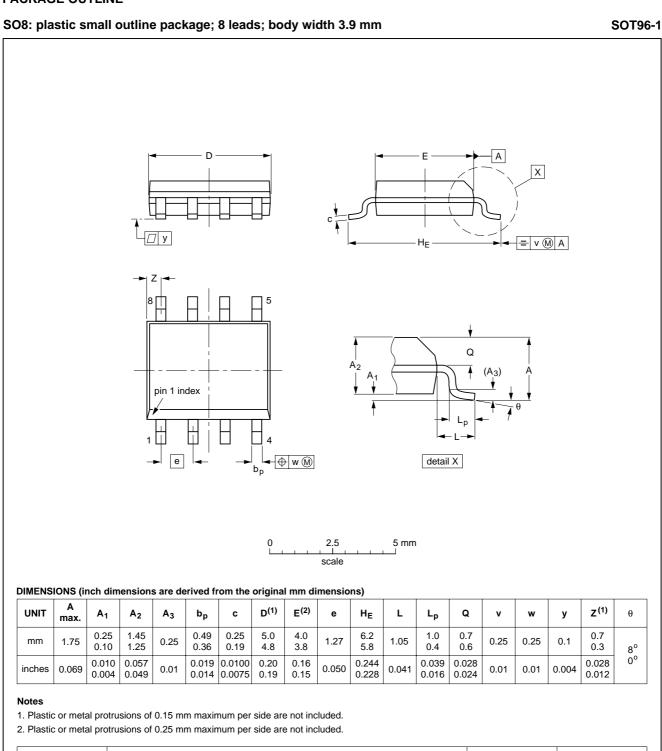
TZA3033

APPLICATION INFORMATION



TZA3033

PACKAGE OUTLINE



OUTLINE	UTLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT96-1	076E03S	MS-012AA				95-02-04 97-05-22	

TZA3033

SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

Wave soldering

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

TZA3033

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
more of the limiting values n of the device at these or at a	Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application information is given, it is advisory and does not form part of the specification.					

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Middle East: see Italy

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South America: Al. Vicente Pinzon, 173, 6th floor, 04547-130 SÃO PAULO, SP, Brazil, Tel. +55 11 821 2333, Fax. +55 11 821 2382

Spain: Balmes 22, 08007 BARCELONA, Tel. +34 93 301 6312, Fax. +34 93 301 4107

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Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1, TAIPEI, Taiwan Tel. +886 2 2134 2865, Fax. +886 2 2134 2874

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Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL, Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7, 252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

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